



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In the application of:

Kunihiro TAKATANI

Serial No.: 09/557,961

Filing Date: April 25, 2000

For: ELECTRODE STRUCTURE ON P-TYPE
III GROUP NITRIDE SEMICONDUCTOR
LAYER AND FORMATION METHOD
THEREOF

Examiner: Donghee Kang

Group Art Unit: 2811

2811
H23/D
10/2/03

AHNL

AMENDMENT UNDER 37 CFR 1.111

Mail Stop Amendment
Commissioner for Patents
2011 South Clark Place
Room 1B03, Crystal Plaza 2
Arlington, VA 22202

Sir:

In response to the Office Action dated May 19, 2003, please amend this application as follows:

10/03/2003 ASMITH 00000001 031952 09557961
01 FC:1201 84.00 DA

RECEIVED
SEP 29 2003
TECHNOLOGY CENTER 2800

va-43030

Serial No.: 09/557,961
Docket No.: 245402001600